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SOGA et al.(10) **Pub. No.: US 2022/0416728 A1**(43) **Pub. Date: Dec. 29, 2022**(54) **POWER AMPLIFIER CIRCUIT**(71) Applicant: **Murata Manufacturing Co., Ltd.**,
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ABSTRACT

A power amplifier circuit includes: a transistor which is supplied at a base with a bias current, amplifies an input signal, and outputs a current; a transistor which is connected at a base to the base of the transistor and in which a current commensurate with the current is input to a collector; a transistor which outputs a bias control signal which controls supply of the bias current; and a control circuit which is connected to the collector of the transistor and a gate of the transistor and controls a bias control signal on the basis of a reference current based on a reference signal and the current.

